

Developments in electronics for HEP

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Based on material produced in the framework of forming the DRD7 collaboration on electronics 2nd DRD7 workshop: <u>https://indico.cern.ch/event/1318635/timetable/#20230925</u>

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Electronics in HEP

- Electronics is ubiquitous in modern HEP experiments
 - Hardware and Software are massively enabling technologies...
 - ... but are becoming major cost drivers and risk factors
- Dynamic and diverse community
 - Prolific
 - Designed ~40 FE ASICs for HL-LHC
 - Developed several large data acquisition and processing systems based on state-of-the-art commercial FPGAs and processors
 - Organized
 - common frameworks for accessing technologies and tools...
 - Topical Workshop for Electronics in Particle Physics (TWEPP)
 - ... but suffering from fragmented resources, becoming subcritical in several areas
- Ambitious detector projects with demanding requirements on electronics
 - Favorable, long term (10+ years) visibility and funding...
 - ... widening gap between technology cycles and detector development time & complexity
- Concern that the current operating model in the community is not sustainable





1. Detector Requirements

- Improved granularity
 - More channels, more data
- Improved precision
 - More data
- Simultaneous space, time & energy tagging
 - More data, High accuracy timing distribution
- Low power
 - More advanced technology nodes, clever designs, efficient power distribution and conversion
- Advanced data handling
 - More intelligence, programmability and configurability
- System-level design
 - Co-optimization of sensors, electronics and algorithms
- Resistance to harsh environments





2. Technologies





COTS or Full-Custom Technologies ?



DAQ systems increasingly COTS-based. Economies of scale, standardization, short upgrade cycles

Exploding software effort, huge complexity and maintenance challenge

Full custom ASICs essential for Front-Ends Optimal functionality, efficiency and rad tolerance Complexity and cost of technology and tools are increasing and becoming unbearable



data from:

https://www.tsmc.com/english/dedicatedFoundry/technology/logic/l_3nm https://irds.ieee.org/editions/2022/more-moore









Example project in DRD7.2



Provide a reference model for verification

Refine specifications and

DRD 7.2.c

Goals

end, to:

prototyping

Provide a virtual prototyping environment for new features development

Reference mode C

Backend systems and COTs

Complex imaging ASICs

Extreme environments





Example project in DRD7.6

DRD 7.6.b Common access to 3D Strategic Goal

- Provide/facilitate the access to advanced chiplet and 3D integration technologies
- Integration of SiPh chip and optical fibers on detector module
 - Reduce development costs and production time by in-house facilities

Performance Targets

- Shared competences/experiences and infrastructures/processes
- Built-up and maintain capability for wafer stacking/multi-tier, chiplet and SiPh integration
 4D & 5D techniques

Supported Technologies

- TSV-last and redistribution layer (RDL) technologies
- Chiplet, 3D/2.5D integration, W2W, C2W and C2C bonding w/wo solder
- Integration of monolithic/hybrid PIC on detector



Data density and efficiency

Intelligence on-detector

Backend systems and COTs

Complex imaging ASICs

Extreme environments

 \Rightarrow DRD 7.1 \Leftrightarrow DRD 7.6



Example project in DRD7.4

R&D priorities





Data density and efficiency

Motivation for the Project "7.4.a Modeling and Development of Cryogenic CMOS PDKs"

- CMOS Process Design Kits typically valid down to 233K (-40°C), although models scale relatively well down to 77K. This was verified with VDSM bulk and FDSOI technology nodes.
- Cold CMOS PDKs are fundamental for the development of complex mixed-signal ASICs allowing for innovative detector architecture and concepts, data transfer, readout and control.
- The sweet spot around LN boiling temperature (where we get the best of the MOSFET characteristics with still no saturation effects) opens promising prospects on the development of innovative readout concepts both for neutrino and dark matter detectors with noble liquids and, in general, for calorimeters and photon detectors operating at 77K.
- The growing interest on the use of CMOS for Quantum Computing and Quantum Sensing could open new opportunities for collaborative efforts with selected silicon foundries on the optimisation of solid-state sensors and CMOS processes for operation at cryogenic temperatures.

4D & 5D techniques

Intelligence on-detector

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- 64 institutes in 15 countries expressed interest to contribute to DRD7
 - Many more observing
- Maintain active community despite the complexity challenge
 - ASICs developments for HL-LHC have been first to show near-failures, but optics, FPGA, soft/firmware are close
 - Complexity trend will continue, and costs will inflate
 - Community must act and restructure to decrease risk
 - Collaborate more, on fewer projects
 - Simulate more before implementing, verify from the beginning
 - Apply system design approaches
 - Specify, develop and document with high-level synthesis tools
- Coordinate cross-community access to technologies, tools and knowledge
 - Share and re-use IP
 - Maintain existing and develop new common frameworks to access advanced technologies and share expertise
 - Develop support hubs to assist smaller teams
 - Introduce rolling reviews



Electronics R&D for HEP





- EPPS strategy update 2020: <u>https://indico.cern.ch/event/957057/</u>
- ECFA Detector R&D: <u>https://indico.cern.ch/event/957057/</u>
- ECFA DRD Roadmap: <u>https://indico.cern.ch/event/957057/page/23281-the-roadmap-document</u>
- 1st DRD7 workshop: <u>https://indico.cern.ch/event/1214423/timetable/#20230314</u>
- 2nd DRD7 workshop: <u>https://indico.cern.ch/event/1318635/timetable/#20230925</u>



Additional material



Data

density

on the

4D-

detector

Extreme

Emerging

TF7 Recommendations

a) Detector R&D Themes, Electronics



* LHCb Velo



